

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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**EOL announced Product**

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# DATA SHEET



# MOS FIELD EFFECT TRANSISTOR 2SK2498

## SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

### DESCRIPTION

2SK2498 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

### FEATURES

- Super Low On-State Resistance  
 $R_{DS(on)1} \leq 9 \text{ m}\Omega$  ( $V_{GS} = 10 \text{ V}$ ,  $I_D = 25 \text{ A}$ )  
 $R_{DS(on)2} \leq 14 \text{ m}\Omega$  ( $V_{GS} = 4 \text{ V}$ ,  $I_D = 25 \text{ A}$ )
- Low  $C_{iss}$   $C_{iss} = 3400 \text{ pF TYP.}$
- High Avalanche Capability Ratings
- Isolate TO-220 Package
- Built-in G-S Protection Diode

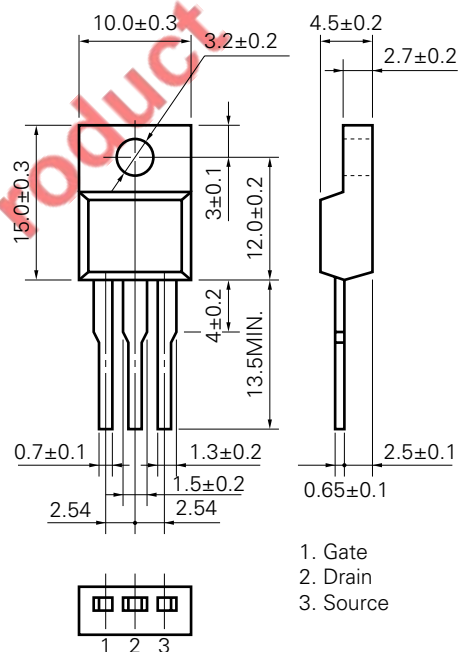
### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25 \text{ }^\circ\text{C}$ )

Drain to Source Voltage	$V_{DSS}$	60	V
Gate to Source Voltage	$V_{GSS}$	$\pm 20$	V
Drain Current (DC)	$I_{D(DC)}$	$\pm 50$	A
Drain Current (pulse)*	$I_{D(pulse)}$	$\pm 200$	A
Total Power Dissipation ( $T_c = 25 \text{ }^\circ\text{C}$ )	$P_{T1}$	35	W
Total Power Dissipation ( $T_A = 25 \text{ }^\circ\text{C}$ )	$P_{T2}$	2.0	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Single Avalanche Current**	$I_{AS}$	50	A
Single Avalanche Energy**	$E_{AS}$	250	mJ

\*  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1 \%$

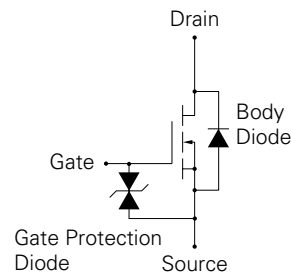
\*\* Starting  $T_{ch} = 25 \text{ }^\circ\text{C}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \text{ V} \rightarrow 0$

### PACKAGE DIMENSIONS (in millimeter)



1. Gate
2. Drain
3. Source

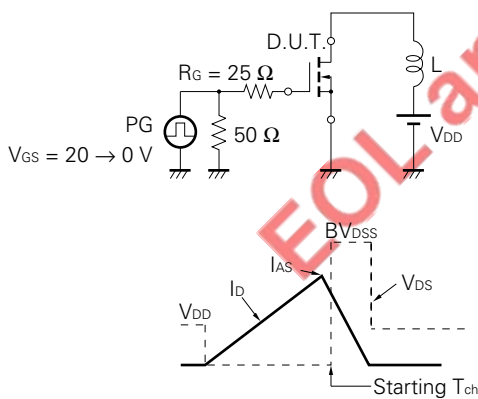
### MP-45F (ISOLATED TO-220)



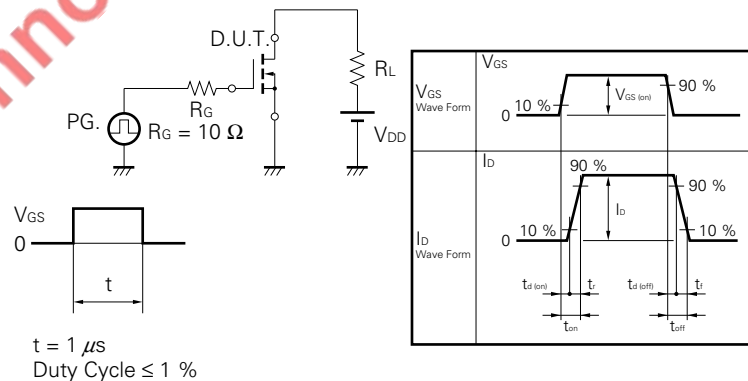
**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)**

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	R <sub>DS(on)1</sub>		7.3	9.0	mΩ	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 25 A
	R <sub>DS(on)2</sub>		11	14	mΩ	V <sub>GS</sub> = 4 V, I <sub>D</sub> = 25 A
Gate to Source Cutoff Voltage	V <sub>GS(off)</sub>	1.0	1.5	2.0	V	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA
Forward Transfer Admittance	y <sub>fs</sub>	20	58		S	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 25 A
Drain Leakage Current	I <sub>DSS</sub>			10	μA	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0
Gate to Source Leakage Current	I <sub>GSS</sub>			±10	nA	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0
Input Capacitance	C <sub>iss</sub>		3400		pF	V <sub>DS</sub> = 10 V
Output Capacitance	C <sub>oss</sub>		1600		pF	V <sub>GS</sub> = 0
Reverse Transfer Capacitance	C <sub>rss</sub>		770		pF	f = 1 MHz
Turn-On Delay Time	t <sub>d(on)</sub>		55		ns	I <sub>D</sub> = 25 A
Rise Time	t <sub>r</sub>		360		ns	V <sub>GS(on)</sub> = 10 V
Turn-Off Delay Time	t <sub>d(off)</sub>		480		ns	V <sub>DD</sub> = 30 V
Fall Time	t <sub>f</sub>		360		ns	R <sub>G</sub> = 10 Ω
Total Gate Charge	Q <sub>G</sub>		152		nC	I <sub>D</sub> = 50 A
Gate to Source Charge	Q <sub>GS</sub>		11		nC	V <sub>DD</sub> = 48 V
Gate to Drain Charge	Q <sub>GD</sub>		60		nC	V <sub>GS</sub> = 10 V
Body Diode Forward Voltage	V <sub>F(S-D)</sub>		0.92		V	I <sub>F</sub> = 50 A, V <sub>GS</sub> = 0
Reverse Recovery Time	t <sub>rr</sub>		105		ns	I <sub>F</sub> = 50 A, V <sub>GS</sub> = 0
Reverse Recovery Charge	Q <sub>rr</sub>		265		μC	di/dt = 100 A/μs

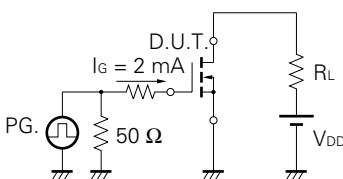
**Test Circuit 1 Avalanche Capability**



**Test Circuit 2 Switching Time**



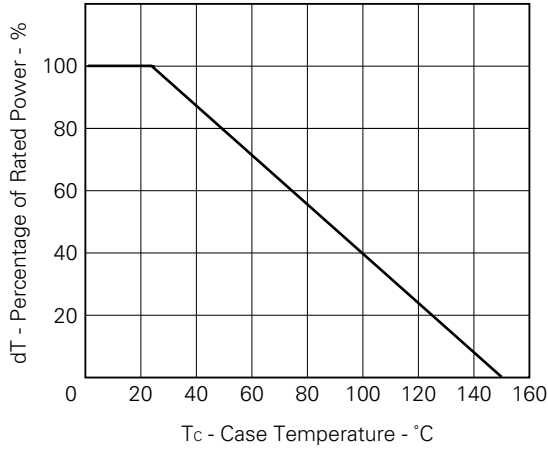
**Test Circuit 3 Gate Charge**



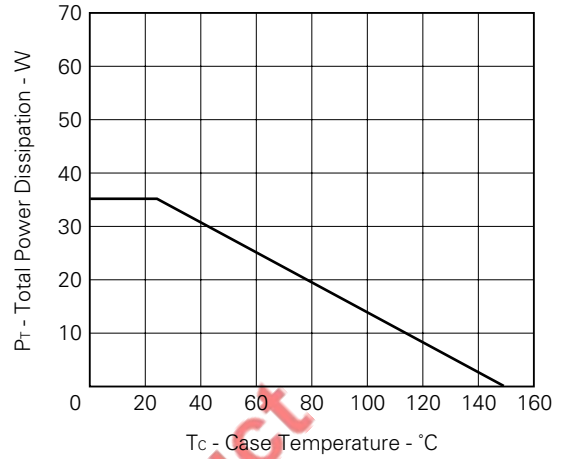
The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

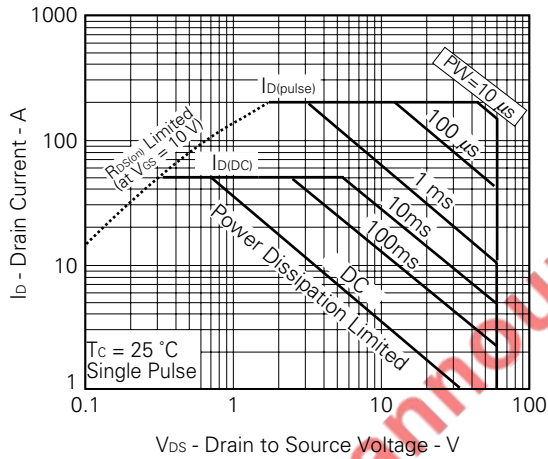
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



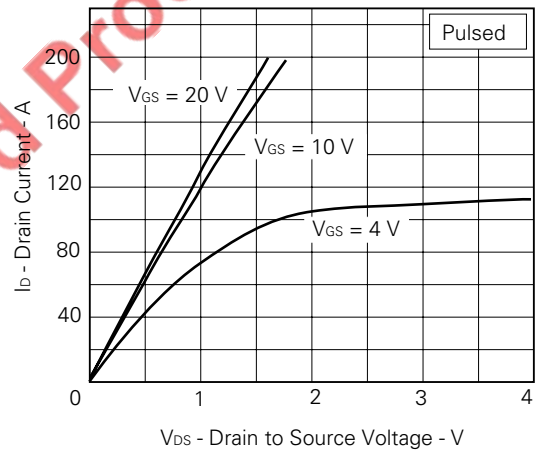
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



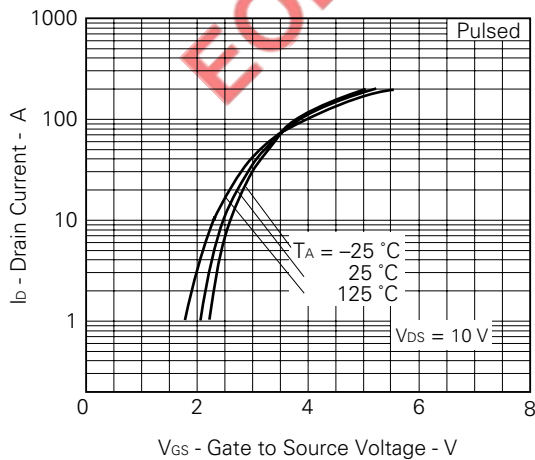
FORWARD BIAS SAFE OPERATING AREA



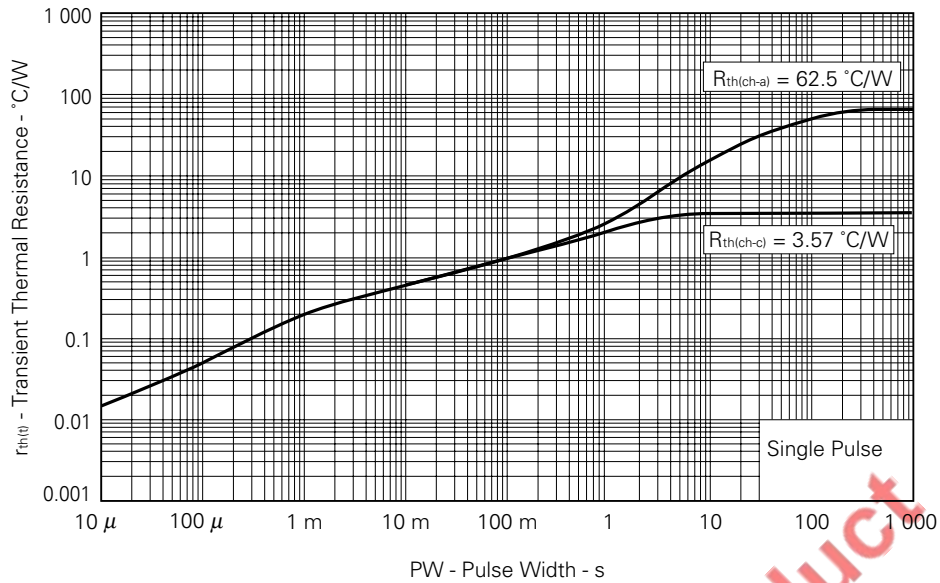
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



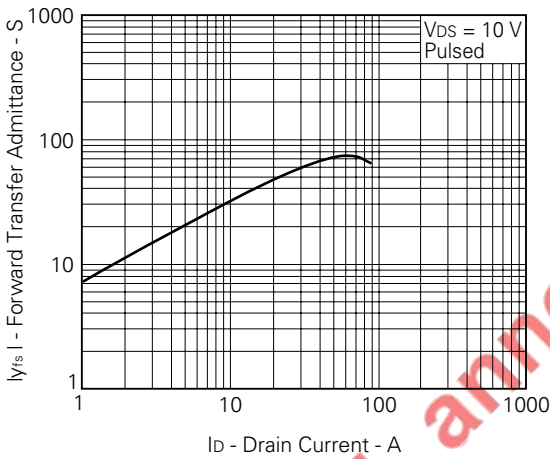
FORWARD TRANSFER CHARACTERISTICS



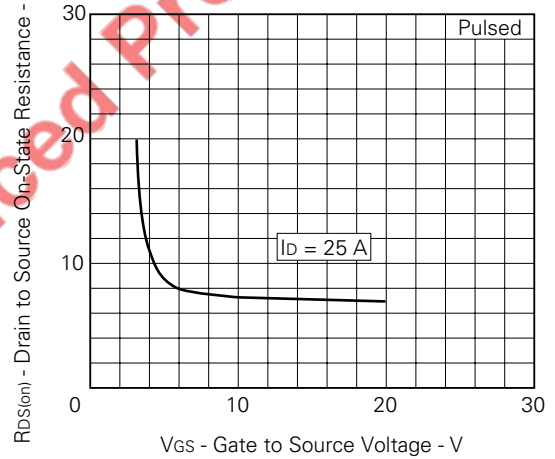
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



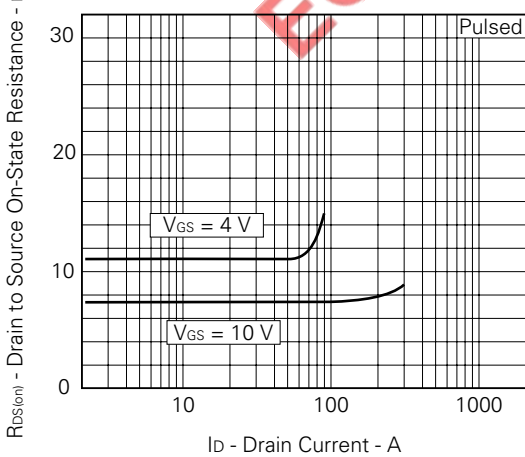
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



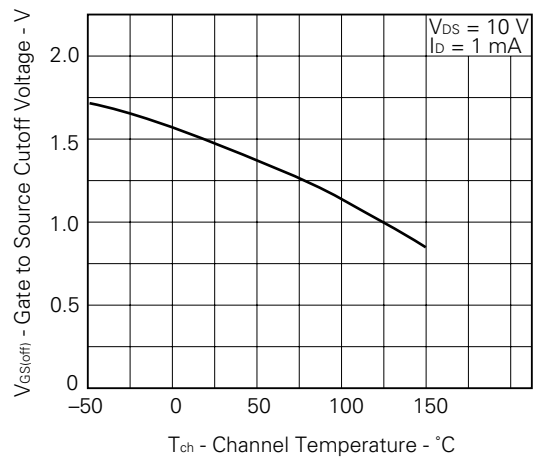
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



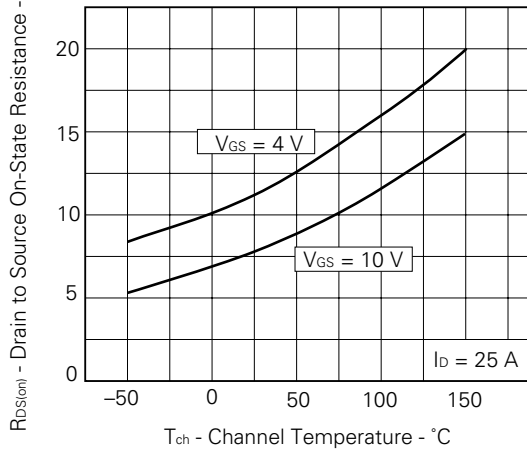
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



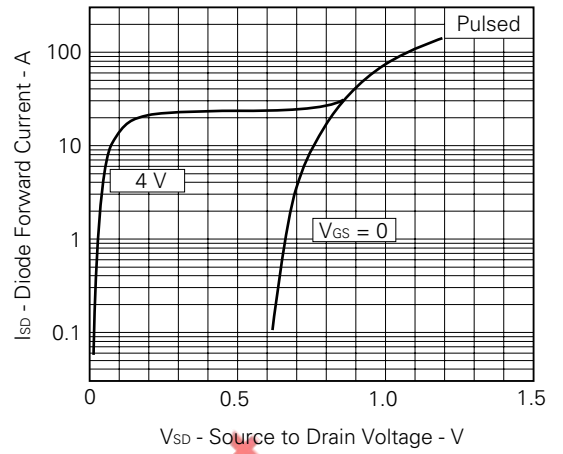
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE



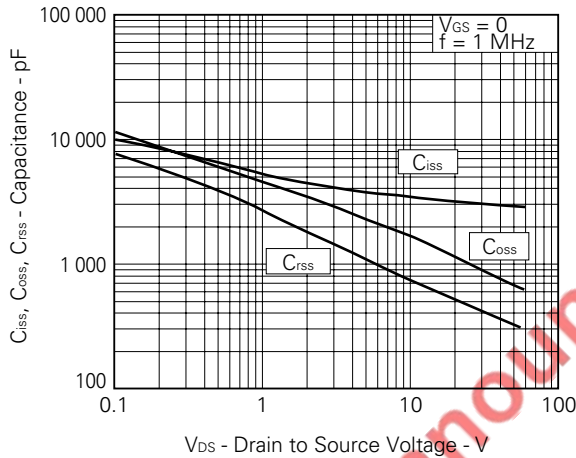
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



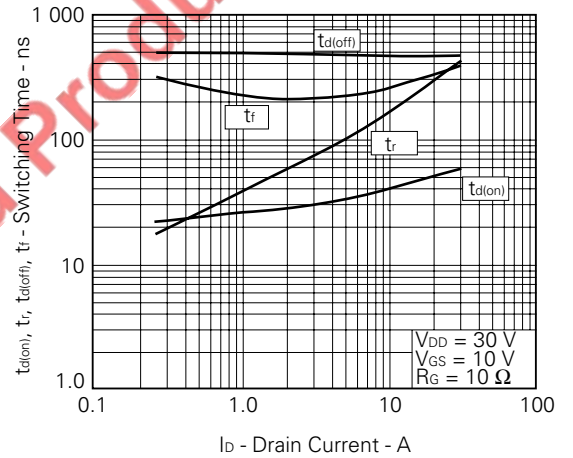
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



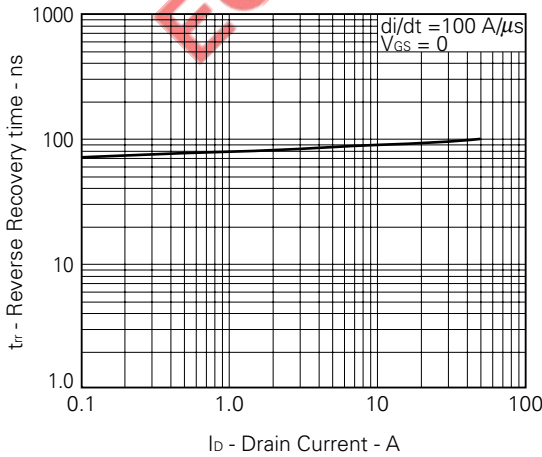
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



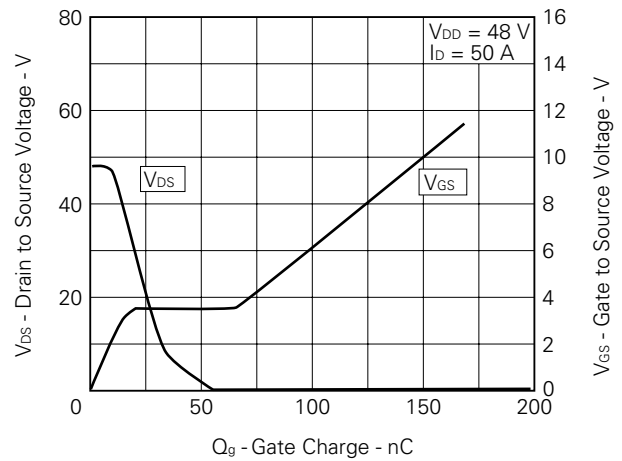
SWITCHING CHARACTERISTICS

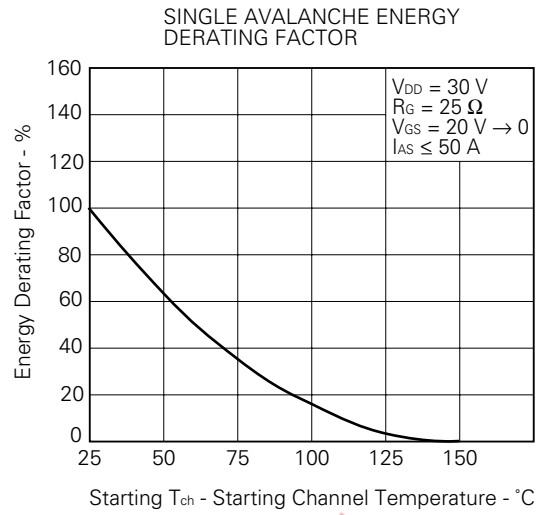
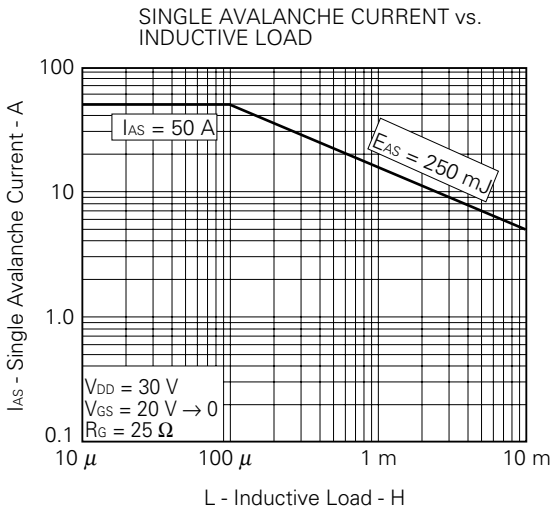


REVERSE RECOVERY TIME vs. DRAIN CURRENT



DYNAMIC INPUT/OUTPUT CHARACTERISTICS





EOL announced Product



**REFERENCE**

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

**EOL announced Product**

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[IRF100S201](#) [JANTX2N5237](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [FCA20N60\\_F109](#) [FDZ595PZ](#) [STD6600NT4G](#) [FSS804-TL-E](#) [2SJ277-DL-E](#)  
[2SK1691-DL-E](#) [2SK2545\(Q,T\)](#) [D2294UK](#) [405094E](#) [423220D](#) [MCH6646-TL-E](#) [TPCC8103,L1Q\(CM](#) [367-8430-0972-503](#) [VN1206L](#)  
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